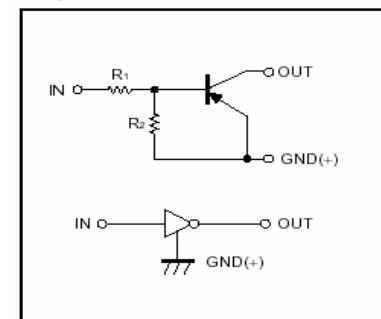


DIGITAL TRANSISTOR (PNP)

Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making device design easy.

● Equivalent circuit



PIN CONNECTIONS AND MARKING

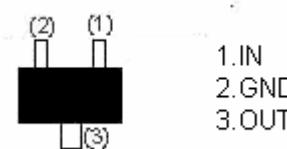
DTA124EE



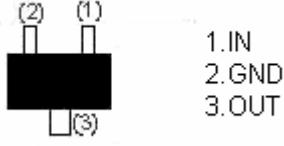
SOT-523

Addreviated symbol: 15

DTA124EUA



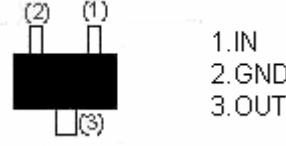
DTA124EKA



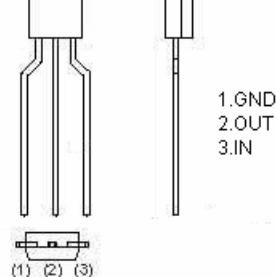
SOT-23-3L

Addreviated symbol: 15

DTA124ECA



DTA124ESA



TO-92S

Addreviated symbol: 15

Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits (DTA124E)					Unit
		E	UA	KA	CA	SA	
Supply voltage	V _{CC}	-50					V
Input voltage	V _{IN}	-40~10					V
Output current	I _O	-30					mA
	I _{C(MAX)}	-100					
Power dissipation	P _d	150		200		300	mW
Junction temperature	T _j	150					°C
Storage temperature	T _{stg}	-55~150					°C

Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V _{I(off)}			-0.5	V	V _{CC} =-5V ,I _O =-100μA
	V _{I(on)}	-3				V _O =-0.2V ,I _O =-5 mA
Output voltage	V _{O(on)}			-0.3	V	I _O /I _I =-10mA/-0.5mA
Input current	I _I			-0.36	mA	V _I =-5V
Output current	I _{O(off)}			-0.5	μA	V _{CC} =-50V ,V _I =0
DC current gain	G _I	56				V _O =-5V ,I _O =-5mA
Input resistance	R _I	15.4	22	28.6	KΩ	
Resistance ratio	R ₂ /R ₁	0.8	1	1.2		
Transition frequency	f _T		250		MHz	V _O =-10V ,I _O =-5mA,f=100MHz

Typical Characteristics

DTA124EE/EUA/EKA/ESA/ECA

●Electrical characteristic curves

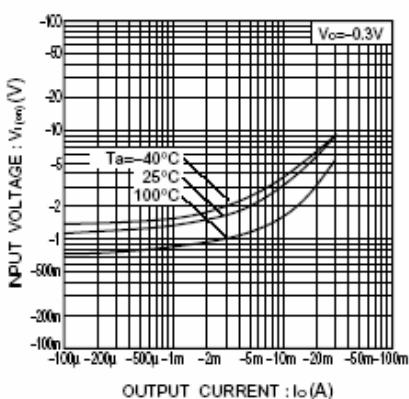


Fig.1 Input voltage vs. output current (ON characteristics)

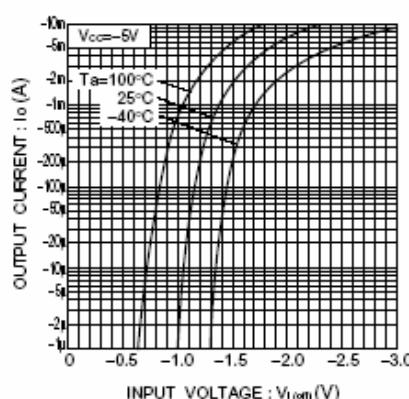


Fig.2 Output current vs. input voltage (OFF characteristics)

